



LMV722-Q1 10MHz、低ノイズ、低電圧オペアンプ

1 特長

- 車載アプリケーションに対応
- 下記内容でAEC-Q100認定済み：
 - デバイスの動作時周囲温度：
-40°C ~ +125°C
 - デバイスHBM ESD分類レベル2
 - デバイスCDM ESD分類レベルC4B
- 電源電圧範囲: 2.2V ~ 5.5V
- 低消費電流: 2.2Vでアンプごとに905µA
- 高いユニティ・ゲイン帯域幅: 10MHz
- レール・ツー・レール出力
 - 600Ω負荷: 2.2V時、各レールから120mV
 - 2kΩ負荷: 2.2V時、各レールから50mV
- 入力同相電圧範囲にグラウンドを含む
- 入力電圧ノイズ: $f = 1\text{kHz}$ で $10.5\text{nV}/\sqrt{\text{Hz}}$

2 アプリケーション

- インフォテインメント
- エンジン制御ユニット
- 車載照明
- オーディオ信号パス

3 概要

LMV722-Q1デバイスは低ノイズ、低電圧のオペアンプで、広範なアプリケーションの設計に組み入れることができます。LMV722-Q1はユニティ・ゲイン帯域幅が10MHz、スルー・レートが $5.25\text{V}/\mu\text{s}$ で、電圧および電流のノイズ特性が優れています。

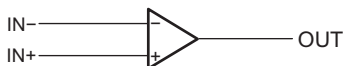
LMV722-Q1は、オーディオ信号パスやモータ制御アプリケーションなど、低電圧で低ノイズのシステムにおいて最適な性能を発揮するように設計されています。このデバイスは、重負荷へもレール・ツー・レール出力を供給します。入力同相電圧範囲にグラウンドが含まれ、デバイスの最大入力オフセット電圧は3.5mV (推奨温度範囲全体にわたって)です。低い電源電圧における容量性負荷能力も優れています。動作電圧範囲は2.2V ~ 5.5Vです。

製品情報⁽¹⁾

型番	パッケージ	本体サイズ(公称)
LMV722-Q1	VSSOP	3.00mm×3.00mm

(1) 提供されているすべてのパッケージについては、巻末の注文情報を参照してください。

概略回路図



目次

1	特長	1	7.4	Device Functional Modes.....	12
2	アプリケーション	1	8	Application and Implementation	13
3	概要	1	8.1	Application Information.....	13
4	改訂履歴	2	8.2	Typical Application	13
5	Pin Configuration and Functions	3	9	Power Supply Recommendations	15
6	Specifications	4	9.1	Input and ESD Protection	15
6.1	Absolute Maximum Ratings	4	10	Layout	16
6.2	ESD Ratings.....	4	10.1	Layout Guidelines	16
6.3	Recommended Operating Conditions.....	4	10.2	Layout Example	17
6.4	Thermal Information	4	11	デバイスおよびドキュメントのサポート	18
6.5	Electrical Characteristics $V_{CC+} = 2.2\text{ V}$	5	11.1	ドキュメントのサポート	18
6.6	Electrical Characteristics $V_{CC+} = 5\text{ V}$	6	11.2	ドキュメントの更新通知を受け取る方法.....	18
6.7	Typical Characteristics	7	11.3	コミュニティ・リソース	18
7	Detailed Description	12	11.4	商標	18
7.1	Overview	12	11.5	静電気放電に関する注意事項	18
7.2	Functional Block Diagram	12	11.6	Glossary	18
7.3	Feature Description.....	12	12	メカニカル、パッケージ、および注文情報	18

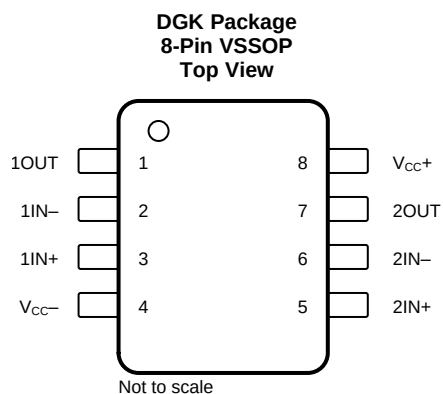
4 改訂履歴

2017年6月発行のものから更新

Page

•	本体サイズを4.90mmから3.00mmに 変更	1
•	CDM value changed from 100 V to 1000 V.....	4
•	Updated <i>Layout Example</i> section	17

5 Pin Configuration and Functions



Pin Functions

PIN		I/O	DESCRIPTION
NO.	NAME		
1	1OUT	O	Output of amplifier 1
2	1IN–	I	Inverting input of amplifier 1
3	1IN+	I	Non-inverting input of amplifier 1
4	V _{CC} –	I	Negative power supply
5	2IN+	I	Non-inverting input of amplifier 2
6	2IN–	I	Inverting input of amplifier 2
7	2OUT	O	Output of amplifier 2
8	V _{CC} +	I	Positive power supply

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
$V_{CC+} - V_{CC-}$	Supply voltage ⁽²⁾	0	6	V
V_{ID}	Differential input voltage ⁽³⁾		±Supply voltage	V
T_J	Operating virtual-junction temperature		150	°C
T_{stg}	Storage temperature	–65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values (except differential voltages and V_{CC} specified for the measurement of I_{OS}) are with respect to the network GND.
- (3) Differential voltages are at IN+ with respect to IN–.

6.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per AEC Q100-002 ⁽¹⁾	2000
		Charged-device model (CDM), per AEC Q100-011	1000

- (1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
$V_{CC+} - V_{CC-}$	Supply voltage	2.2	5.5	V
T_J	Operating ambient temperature	–40	125	°C

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		LMV722-Q1	UNIT
		DGK (VSSOP)	
		8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	176.3	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	69.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	97.7	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	12.7	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	96.3	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics $V_{CC+} = 2.2\text{ V}$

$V_{CC+} = 2.2\text{ V}$, $V_{CC-} = \text{GND}$, $V_{ICR} = V_{CC+}/2$, $V_O = V_{CC+}/2$, and $R_L > 1\text{ M}\Omega$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	$T_J = 25^\circ\text{C}$		0.02	3	mV
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$			3.5	
TCV_{IO}	Input offset voltage average drift	$T_J = 25^\circ\text{C}$		0.6		$\mu\text{V}/^\circ\text{C}$
I_{IB}	Input bias current	$T_J = 25^\circ\text{C}$		260		nA
I_{IO}	Input offset current	$T_J = 25^\circ\text{C}$		25		nA
$CMMR$	Common-mode rejection ratio	$V_{ICR} = 0\text{ V to } 1.3\text{ V}$ $T_J = 25^\circ\text{C}$	70	88		dB
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$	64			
$PSRR$	Power-supply rejection ratio	$V_{CC+} = 2.2\text{ V to } 5\text{ V}$ $V_O = 0$, $V_{ICR} = 0$ $T_J = 25^\circ\text{C}$	80	90		dB
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$	70			
V_{ICR}	Input common-mode voltage	$CMRR \geq 50\text{ dB}$ $T_J = 25^\circ\text{C}$		-0.3		V
		$T_J = 25^\circ\text{C}$		1.3		
A_{VD}	Large-signal voltage gain	$R_L = 600\ \Omega$, $V_O = 0.75\text{ V to } 2\text{ V}$ $T_J = 25^\circ\text{C}$	75	81		dB
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$	70			
		$R_L = 2\text{ k}\Omega$, $V_O = 0.5\text{ V to } 2.1\text{ V}$ $T_J = 25^\circ\text{C}$	75	84		
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$	70			
V_O	Output swing	$R_L = 600\ \Omega\text{ to } V_{CC+}/2$ $T_J = 25^\circ\text{C}$	2.090	2.125		V
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$	2.065			
		$T_J = 25^\circ\text{C}$		0.071	0.120	
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$			0.145	
		$R_L = 2\text{ k}\Omega\text{ to } V_{CC+}/2$ $T_J = 25^\circ\text{C}$	2.150	2.177		
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$	2.125			
		$T_J = 25^\circ\text{C}$		0.056	0.080	
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$			0.105	
I_O	Output current	Sourcing, $V_O = 0\text{ V}$ $V_{IN(\text{diff})} = \pm 0.5\text{ V}$ $T_J = 25^\circ\text{C}$	10	14.9		mA
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$	5			
		Sinking, $V_O = 2.2\text{ V}$ $V_{IN(\text{diff})} = \pm 0.5\text{ V}$ $T_J = 25^\circ\text{C}$	10	17.6		
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$	5			
I_{CC}	Supply current	$T_J = 25^\circ\text{C}$		1.81	2.4	mA
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$			2.6	
SR	Slew rate ⁽¹⁾	$T_J = 25^\circ\text{C}$		4.9		$\text{V}/\mu\text{s}$
GBW	Gain bandwidth product	$T_J = 25^\circ\text{C}$		10		MHz
Φ_m	Phase margin	$T_J = 25^\circ\text{C}$		67.4		°
G_m	Gain margin	$T_J = 25^\circ\text{C}$		-9.8		dB
V_n	Input-referred voltage noise	$f = 1\text{ kHz}$ $T_J = 25^\circ\text{C}$		11		$\text{nV}/\sqrt{\text{Hz}}$
I_n	Input-referred current noise	$f = 1\text{ kHz}$ $T_J = 25^\circ\text{C}$		0.3		$\text{pA}/\sqrt{\text{Hz}}$
THD	Total harmonic distortion	$f = 1\text{ kHz}$, $AV = 1$, $R_L = 600\ \Omega$, $V_O = 500\text{ mV}_{pp}$ $T_J = 25^\circ\text{C}$		0.004%		

(1) Connected as voltage follower with 1-V step input. Number specified is the slower of the positive and negative slew rate.

LMV722-Q1

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6.6 Electrical Characteristics $V_{CC+} = 5\text{ V}$
 $V_{CC+} = 5\text{ V}$, $V_{CC-} = \text{GND}$, $V_{ICR} = V_{CC+}/2$, $V_O = V_{CC+}/2$, and $R_L > 1\text{ M}\Omega$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	$T_J = 25^\circ\text{C}$		–0.08	3	mV
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$			3.5	
TCV_{IO}	Input offset voltage average drift	$T_J = 25^\circ\text{C}$		0.6		$\mu\text{V}/^\circ\text{C}$
I_{IB}	Input bias current	$T_J = 25^\circ\text{C}$		260		nA
I_{IO}	Input offset current	$T_J = 25^\circ\text{C}$		25		nA
CMMR	Common-mode rejection ratio	$V_{ICR} = 0\text{ V to } 4.1\text{ V}$ $T_J = 25^\circ\text{C}$	80	89		dB
		$V_{ICR} = 0\text{ V to } 4.1\text{ V}$ $T_J = -40^\circ\text{C to } +125^\circ\text{C}$	75			
PSRR	Power-supply rejection ratio	$V_{CC+} = 2.2\text{ V to } 5\text{ V}$, $V_O = 0$, $V_{ICR} = 0$ $T_J = 25^\circ\text{C}$	70	90		dB
		$V_{CC+} = 2.2\text{ V to } 5\text{ V}$, $V_O = 0$, $V_{ICR} = 0$ $T_J = -40^\circ\text{C to } +125^\circ\text{C}$	64			
V_{ICR}	Input common-mode voltage	CMRR $\geq 50\text{ dB}$ $T_J = 25^\circ\text{C}$		–0.3		V
		$T_J = 25^\circ\text{C}$		4.1		
A_{VD}	Large-signal voltage gain	$R_L = 600\ \Omega$, $V_O = 0.75\text{ V to } 4.8\text{ V}$ $T_J = 25^\circ\text{C}$	80	87		dB
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$	70			
		$R_L = 2\text{ k}\Omega$, $V_O = 0.7\text{ V to } 4.9\text{ V}$ $T_J = 25^\circ\text{C}$	80	94		
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$	70			
V_O	Output swing	$R_L = 600\ \Omega\text{ to } V_{CC+}/2$ $T_J = 25^\circ\text{C}$	4.84	4.882		V
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$	4.815			
		$T_J = 25^\circ\text{C}$		0.134	0.19	
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$			0.215	
		$R_L = 2\text{ k}\Omega\text{ to } V_{CC+}/2$ $T_J = 25^\circ\text{C}$	4.93	4.952		
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$	4.905			
I_O	Output current	$T_J = 25^\circ\text{C}$	20	52.6		mA
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$	12			
		$T_J = 25^\circ\text{C}$	15	23.7		
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$	8.5			
I_{CC}	Supply current	$T_J = 25^\circ\text{C}$		2.01	2.4	mA
		$T_J = -40^\circ\text{C to } +125^\circ\text{C}$			2.8	
SR	Slew rate ⁽¹⁾	$T_J = 25^\circ\text{C}$		5.25		V/ μs
GBW	Gain bandwidth product	$T_J = 25^\circ\text{C}$		10		MHz
Φ_m	Phase margin	$T_J = 25^\circ\text{C}$		72		°
G_m	Gain margin	$T_J = 25^\circ\text{C}$		–11		dB
V_n	Input-referred voltage noise	$f = 1\text{ kHz}$ $T_J = 25^\circ\text{C}$		10.5		$\text{nV}/\sqrt{\text{Hz}}$
I_n	Input-referred current noise	$f = 1\text{ kHz}$ $T_J = 25^\circ\text{C}$		0.2		$\text{pA}/\sqrt{\text{Hz}}$
THD	Total harmonic distortion	$f = 1\text{ kHz}$, $A_V = 1$, $R_L = 600\ \Omega$, $V_O = 500\text{ mV}_{pp}$ $T_J = 25^\circ\text{C}$		0.001%		

(1) Connected as voltage follower with 1-V step input. Number specified is the slower of the positive and negative slew rate.

6.7 Typical Characteristics

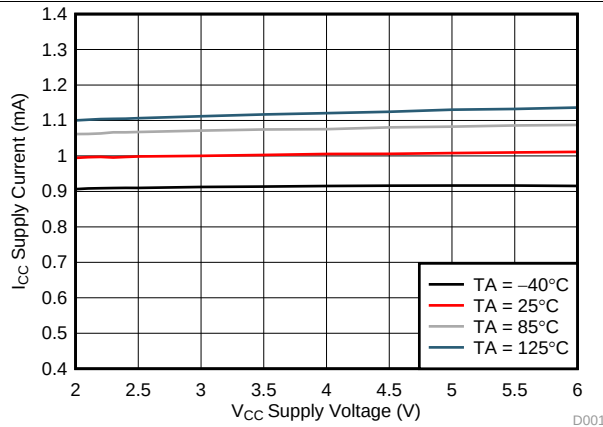


FIG 1. Supply Current vs Supply Voltage

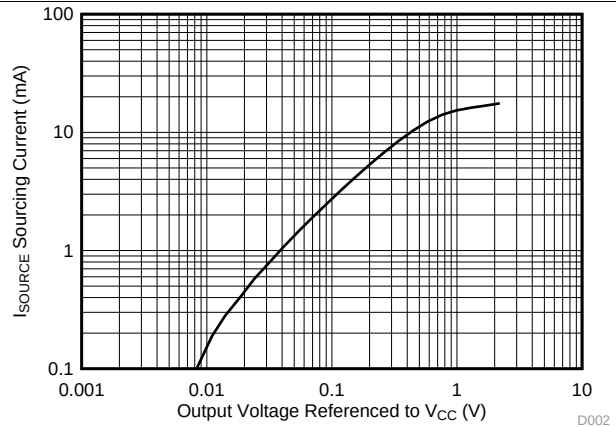


FIG 2. Sourcing Current vs Output Voltage

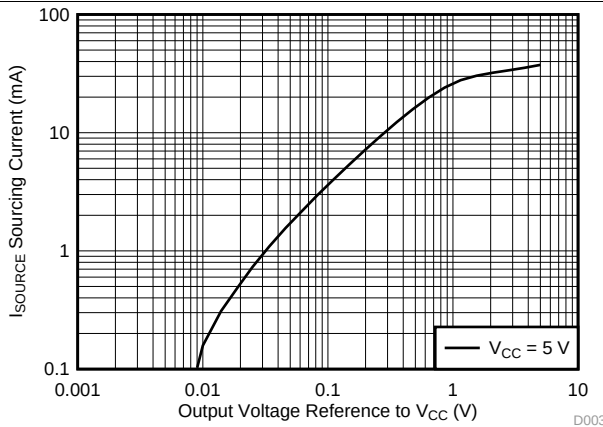


FIG 3. Sourcing Current vs Output Voltage

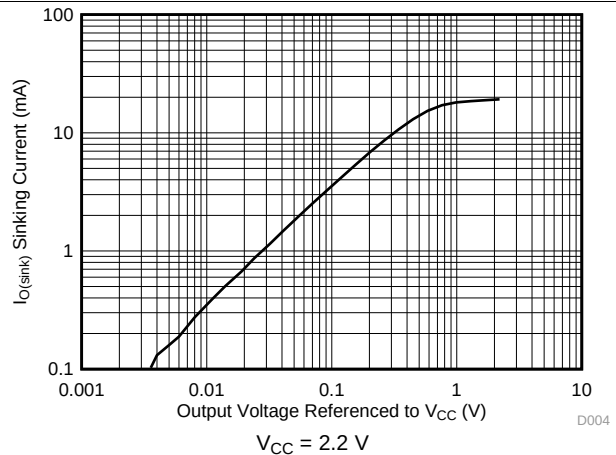


FIG 4. Sinking Current vs Output Voltage

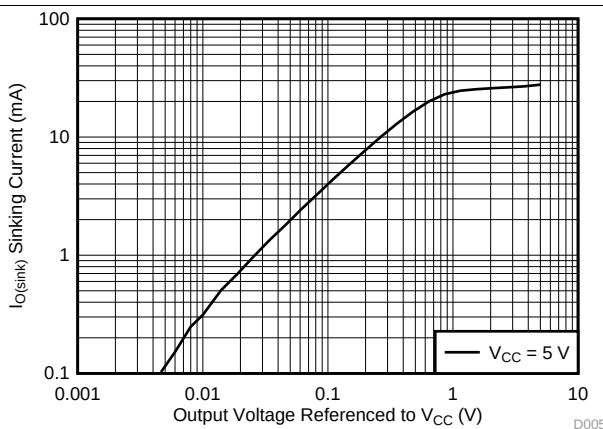


FIG 5. Sinking Current vs Output Voltage

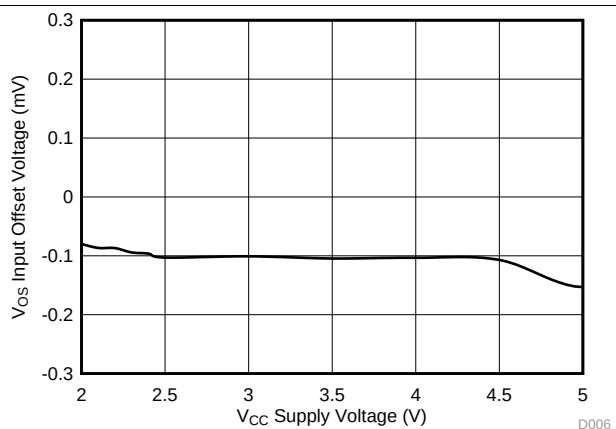


FIG 6. V_{IO} vs Supply Voltage

Typical Characteristics (continued)

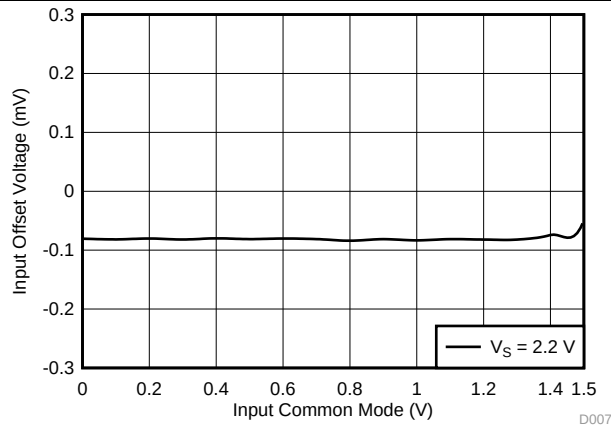


图 7. Input Offset Voltage vs Input Common-Mode Voltage

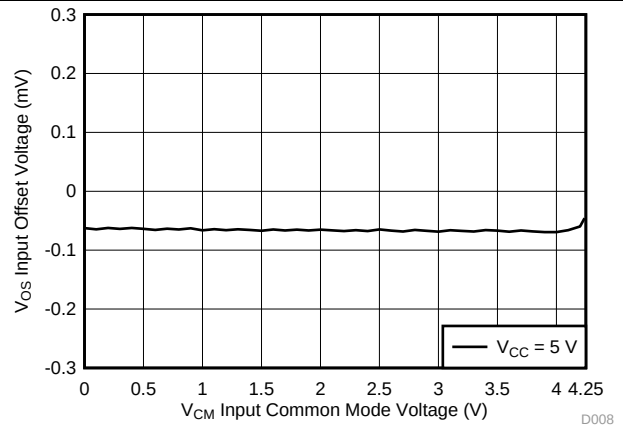


图 8. Input Offset Voltage vs Input Common-Mode Voltage

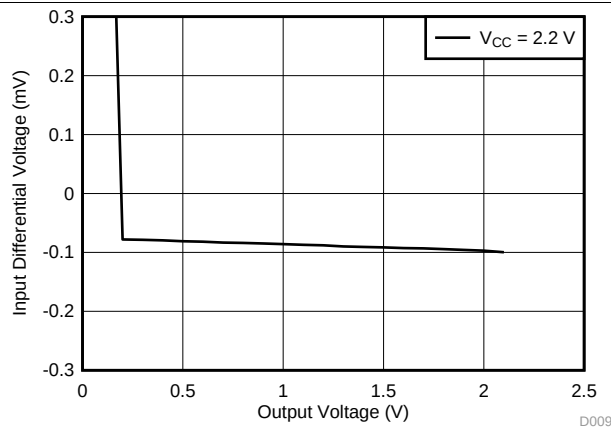


图 9. Input Voltage vs Output Voltage

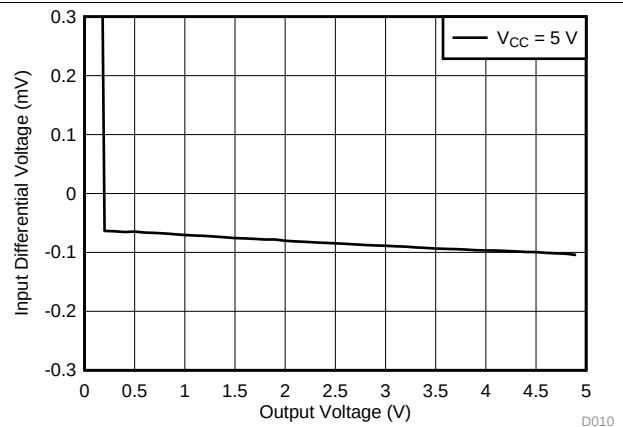


图 10. Input Voltage vs Output Voltage

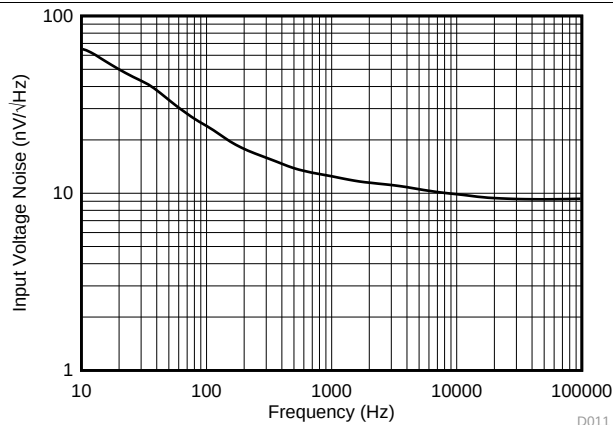


图 11. Input Voltage Noise vs Frequency

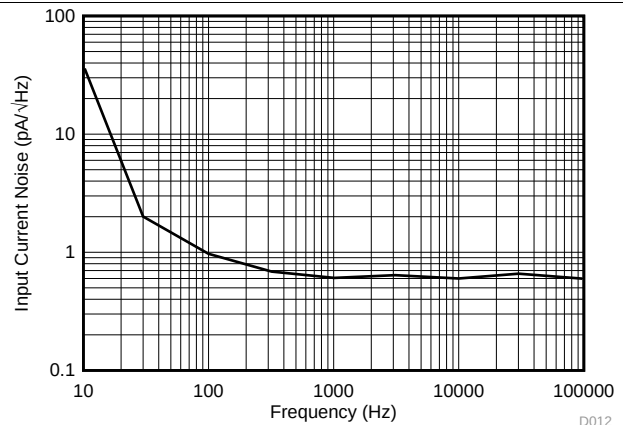


图 12. Input Current Noise vs Frequency

Typical Characteristics (continued)

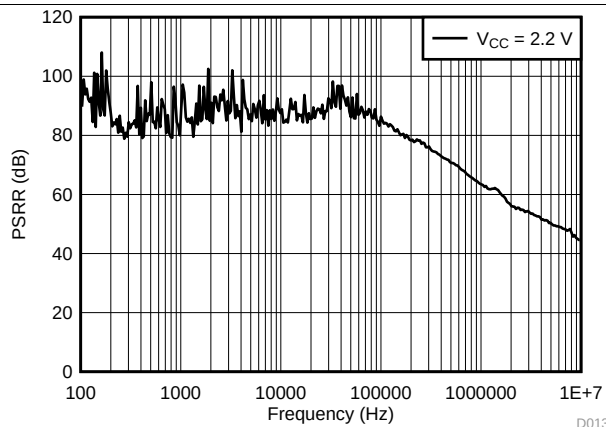


图 13. Psrr vs Frequency

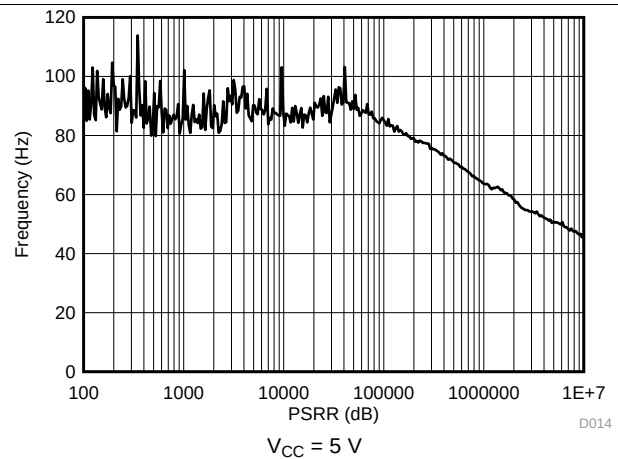


图 14. Psrr vs Frequency

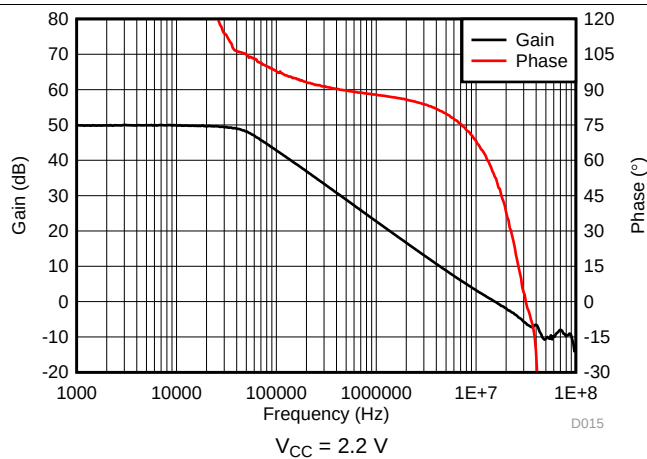


图 15. Gain And Phase vs Frequency

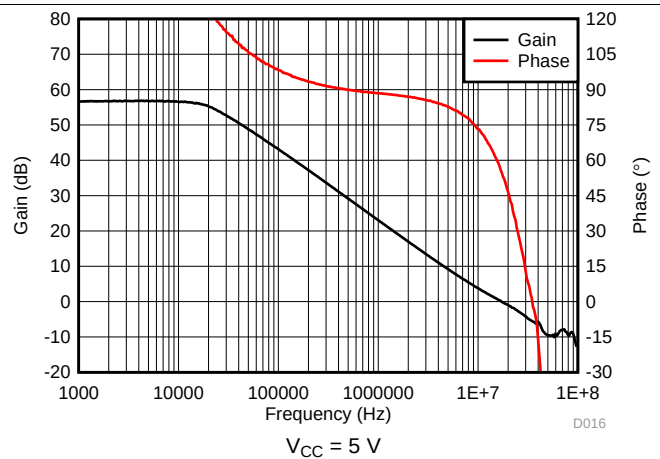


图 16. Gain And Phase vs Frequency

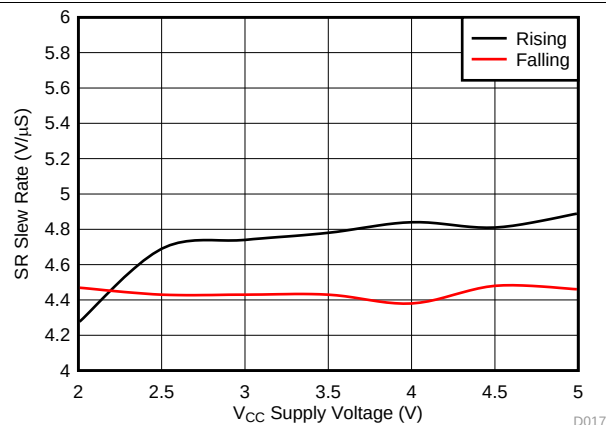


图 17. Slew Rate vs Supply Voltage

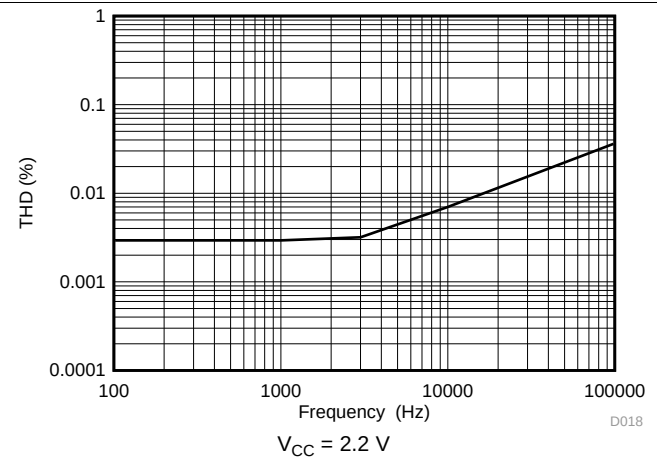


图 18. Thd vs Frequency

Typical Characteristics (continued)

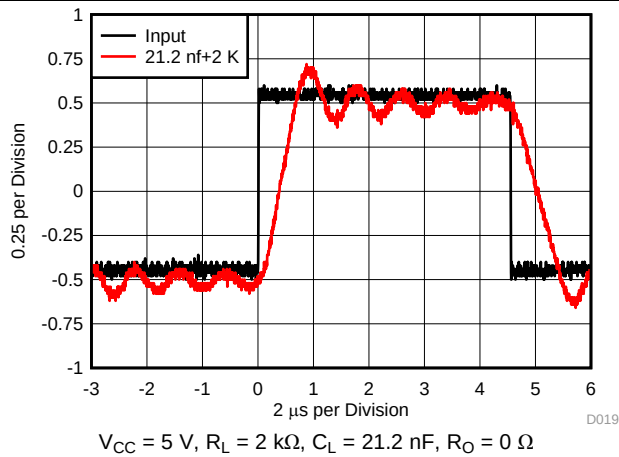


FIG 19. Pulse Response

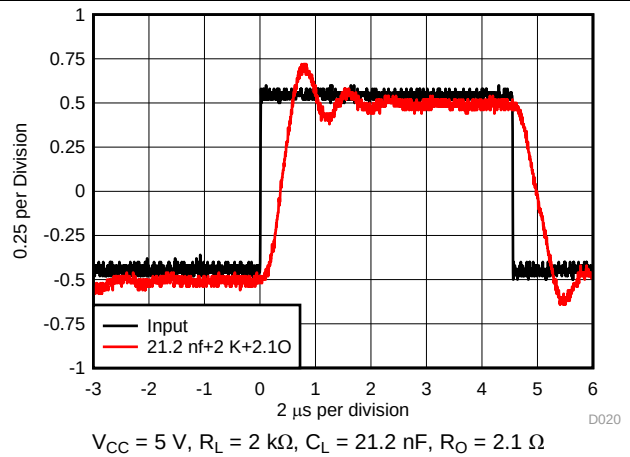


FIG 20. Pulse Response

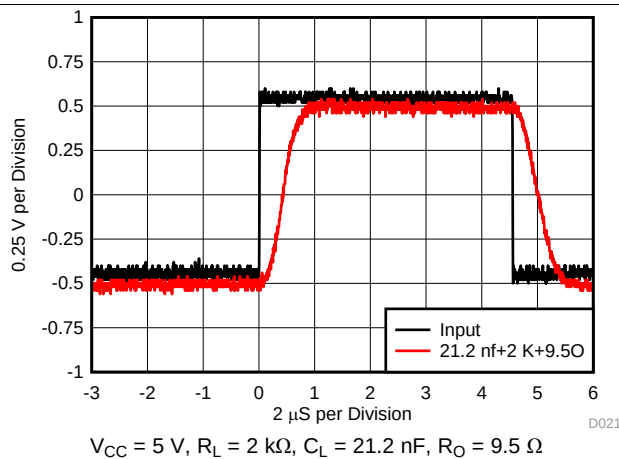


FIG 21. Pulse Response

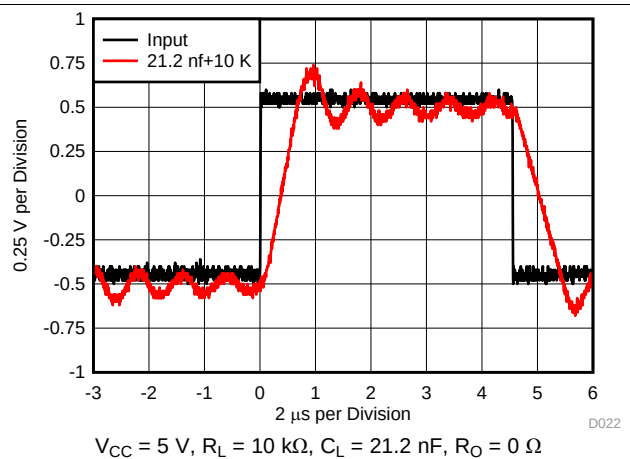


FIG 22. Pulse Response

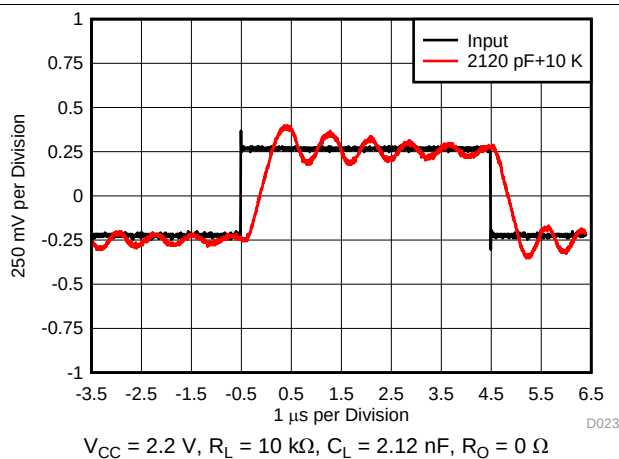


FIG 23. Pulse Response

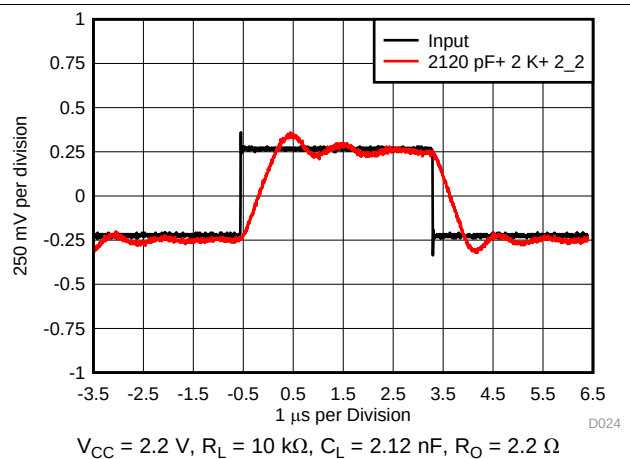
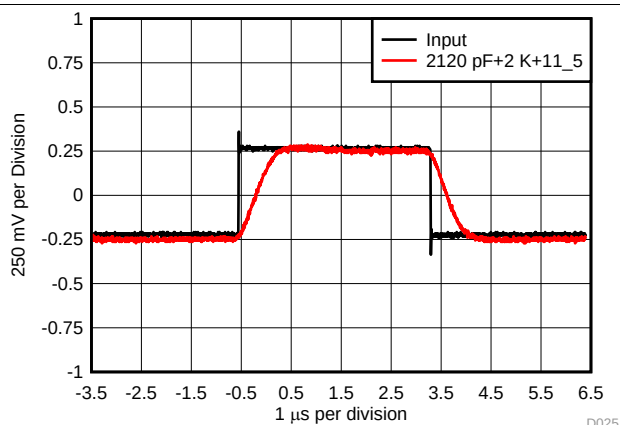


FIG 24. Pulse Response

Typical Characteristics (continued)



$V_{CC} = 2.2 \text{ V}$, $R_L = 10 \text{ k}\Omega$, $C_L = 2.12 \text{ nF}$, $R_O = 11.5 \Omega$

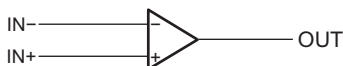
⊠ 25. Pulse Response

7 Detailed Description

7.1 Overview

The LMV722-Q1 is a low-power, low-noise, rail-to-rail output op amp. This device is AEC-Q100 qualified for automotive applications. The LMV722-Q1 operates from a single 2.2 V to 5.5 V supply, is unity-gain stable, and is suitable for a wide range of general-purpose applications. The input common-mode voltage range includes ground. Rail-to-rail input and output swing significantly increases dynamic range in low-supply applications and makes applications suitable for driving sampling analog-to-digital converters (ADCs). The small footprints of the LMV722-Q1 package saves space on printed-circuit boards and enables good signal integrity and noise performance during the design of smaller electronic products, such as automotive head units.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Low Noise

The LMV722-Q1 device is a general-purpose op amp that provides low noise of 10.5 nV/√Hz and a wide bandwidth of 10 MHz. The low noise and wide bandwidth make the LMV722-Q1 device attractive for a variety of precision applications that require a good balance between cost and performance.

7.3.2 Rail-to-Rail Output

Rail-to-rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating on low-supply voltages.

7.3.3 Input Includes Ground

This feature allows direct sensing near GND in a single-supply operation.

7.3.4 Signal Integrity

Signals pick up noise between the signal source and the amplifier. By using a physically smaller amplifier package, such as the 8-pin VSSOP (DGK), the LMV722-Q1 can be placed closer to the signal source; reducing noise pickup and increasing signal integrity.

7.4 Device Functional Modes

The only mode available for the LMV722-Q1 device is *on*.

8 Application and Implementation

注

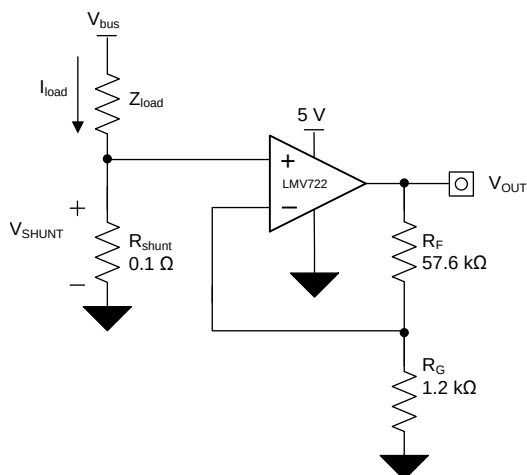
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The LMV722-Q1 features 10-MHz bandwidth and 5.25-V/ μ s slew rate providing good AC performance at very-low-power consumption. DC applications are well served with a very-low input noise voltage of 10.5 nV / $\sqrt{\text{Hz}}$ at 1 kHz, low input bias current, and a typical input offset voltage of 0.02 mV.

8.2 Typical Application

Figure 26 shows the LMV722-Q1 configured in a low-side current sensing application.



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Figure 26. LMV722-Q1 in a Low-Side, Current-Sensing Application

8.2.1 Design Requirements

The design requirements for this design are:

- Load current: 0 A to 1 A
- Output voltage: 4.9 V
- Maximum shunt voltage: 100 mV

Typical Application (continued)

8.2.2 Detailed Design Procedure

The transfer function of the circuit in [Figure 26](#) is given in [Equation 1](#)

$$V_{OUT} = I_{LOAD} \times R_{SHUNT} \times \text{Gain} \quad (1)$$

The load current (I_{LOAD}) produces a voltage drop across the shunt resistor (R_{SHUNT}). The load current is set from 0 A to 1 A. To keep the shunt voltage below 100 mV at maximum load current, the largest shunt resistor is defined using [Equation 2](#).

$$R_{SHUNT} = \frac{V_{SHUNT_MAX}}{I_{LOAD_MAX}} = \frac{100\text{mV}}{1\text{A}} = 100\text{m}\Omega \quad (2)$$

Using [Equation 2](#), R_{SHUNT} is calculated to be 100 mΩ. The voltage drop produced by I_{LOAD} and R_{SHUNT} is amplified by the LMV722-Q1 to produce an output voltage of roughly 0 V to 4.9 V. The gain needed by the LMV722-Q1 to produce the necessary output voltage is calculated using [Equation 3](#):

$$\text{Gain} = \frac{(V_{OUT_MAX} - V_{OUT_MIN})}{(V_{IN_MAX} - V_{IN_MIN})} \quad (3)$$

Using [Equation 3](#), the required gain is calculated to be 49 V/V, which is set with resistors R_F and R_G . [Equation 4](#) is used to size the resistors, R_F and R_G , to set the gain of the LMV722-Q1 to 49 V/V.

$$\text{Gain} = 1 + \frac{(R_F)}{(R_G)} \quad (4)$$

Choosing R_F as 57.6 kΩ and R_G as 1.2 kΩ provides a combination that equals roughly 49 V/V. [Figure 27](#) shows the measured transfer function of the circuit shown in [Figure 26](#).

8.2.3 Application Curve

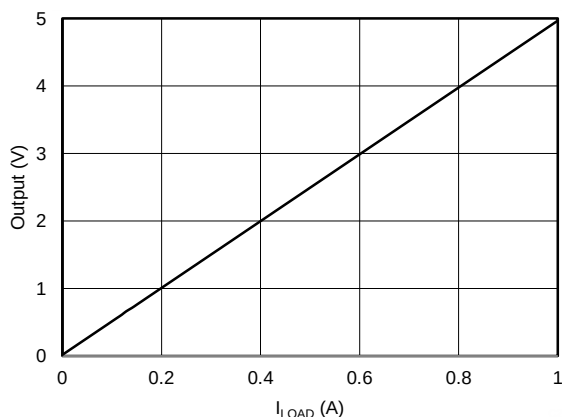


Figure 27. Low-Side, Current-Sense, Transfer Function

9 Power Supply Recommendations

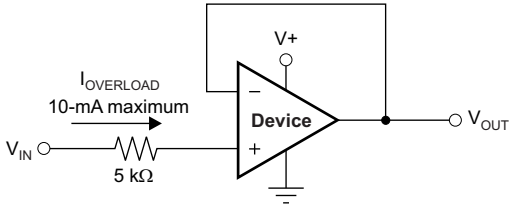
The LMV722-Q1 series is specified for operation from 2.2 V to 5.5 V (± 1.1 V to ± 2.75 V); many specifications apply from -40°C to $+125^{\circ}\text{C}$. The section presents parameters that can exhibit significant variance with regard to operating voltage or temperature.

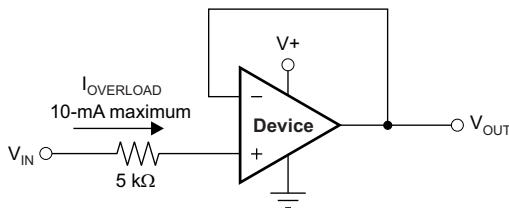
注意

Supply voltages larger than 6 V can permanently damage the device; see the [Absolute Maximum Ratings](#) table.

Place 0.1- μF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, see the section.

9.1 Input and ESD Protection

The LMV722-Q1 incorporates internal ESD protection circuits on all pins. For input and output pins, this protection primarily consists of current-steering diodes connected between the input and power-supply pins. These ESD protection diodes provide in-circuit, input overdrive protection, as long as the current is limited to 10-mA, as stated in the [Layout Guidelines](#) table.  shows how a series input resistor can be added to the driven input to limit the input current. The added resistor contributes thermal noise at the amplifier input and the value must be kept to a minimum in noise-sensitive applications.



 28. Input Current Protection

10 Layout

10.1 Layout Guidelines

For best operational performance of the device, use good printed circuit board (PCB) layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and of op amp itself. Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
 - Connect low-ESR, 0.1- μ F ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for single-supply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces electromagnetic interference (EMI) noise pickup. Make sure to physically separate digital and analog grounds, paying attention to the flow of the ground current. For more detailed information refer to, see [Circuit Board Layout Techniques](#).
- In order to reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, crossing the sensitive trace perpendicular is much better as opposed to in parallel with the noisy trace.
- Place the external components as close to the device as possible. As illustrated in [Figure 30](#), keeping RF and RG close to the inverting input minimizes parasitic capacitance on the inverting input.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.
- Cleaning the PCB following board assembly is recommended for best performance.
- Any precision integrated circuit can experience performance shifts resulting from moisture ingress into the plastic package. Following any aqueous PCB cleaning process, baking the PCB assembly is recommended to remove moisture introduced into the device packaging during the cleaning process. A low-temperature, post-cleaning bake at 85°C for 30 minutes is sufficient for most circumstances.

10.2 Layout Example

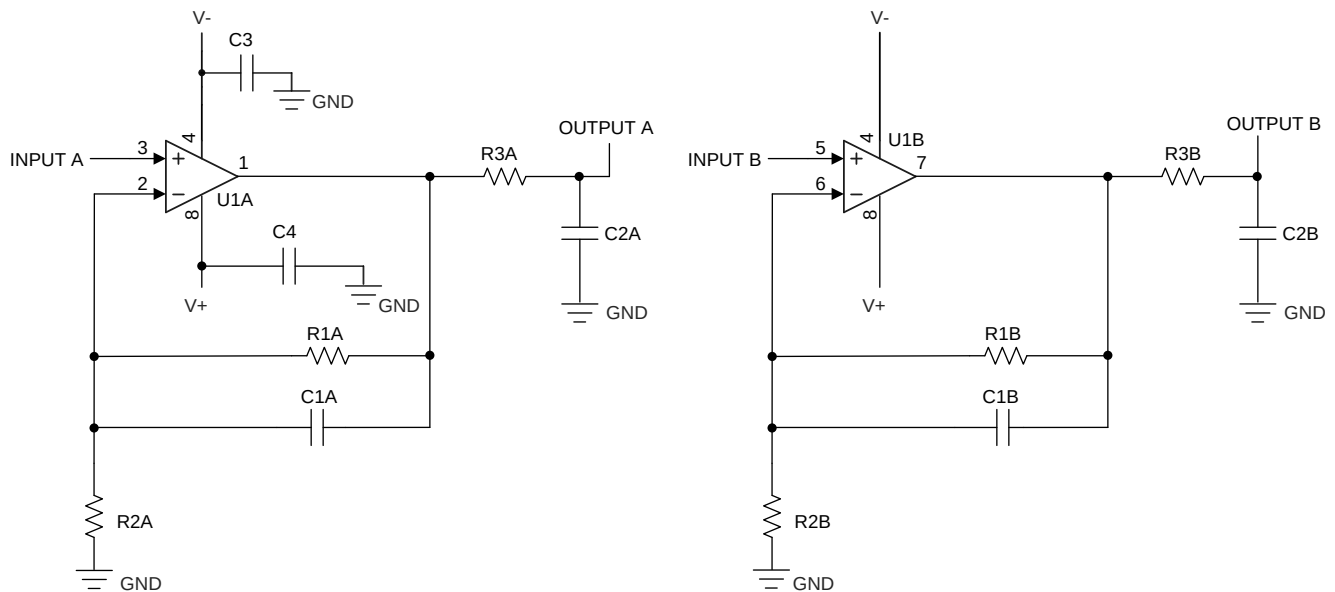


FIG 29. Schematic Representation for FIG 30

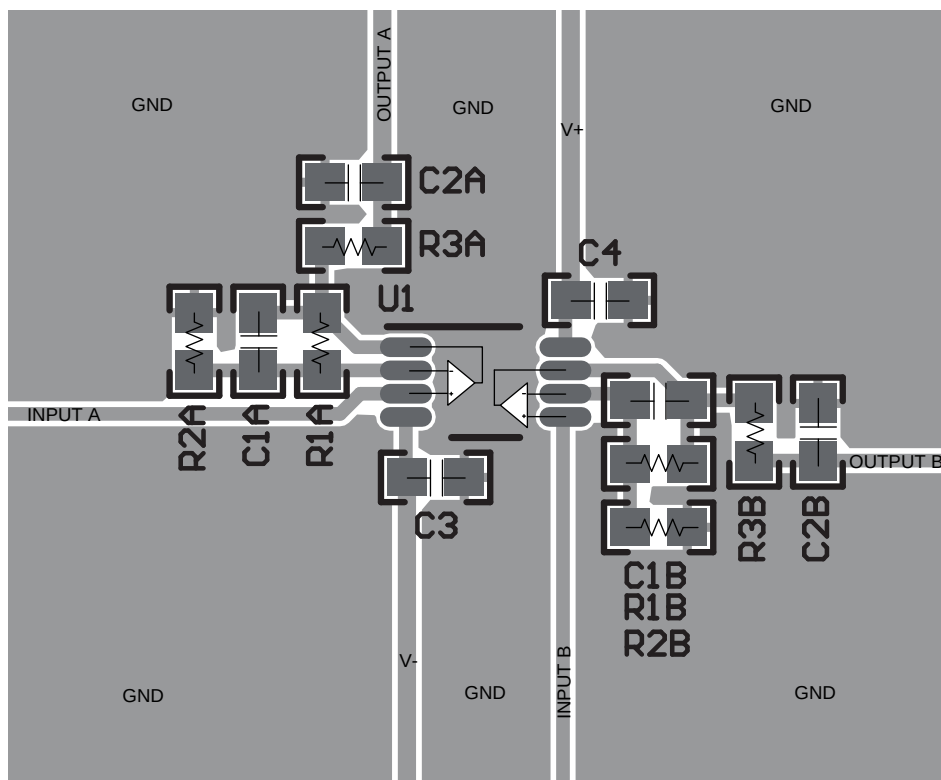


FIG 30. Layout Example

11 デバイスおよびドキュメントのサポート

11.1 ドキュメントのサポート

11.1.1 関連資料

関連資料については、以下を参照してください。

テキサス・インスツルメンツ、[『回路基板のレイアウト技法』](#)

11.2 ドキュメントの更新通知を受け取る方法

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11.6 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 メカニカル、パッケージ、および注文情報

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LMV722QDGKRQ1	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	R6EQ
LMV722QDGKRQ1.A	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	R6EQ

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF LMV722-Q1 :

- Catalog : [LMV722](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV722QDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



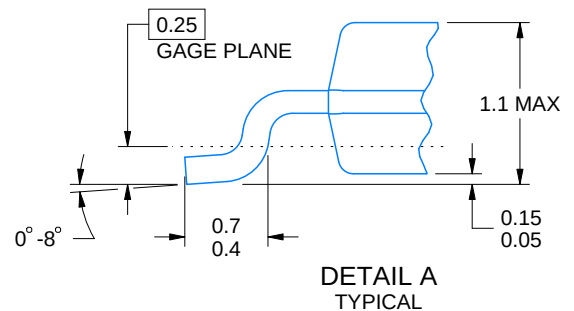
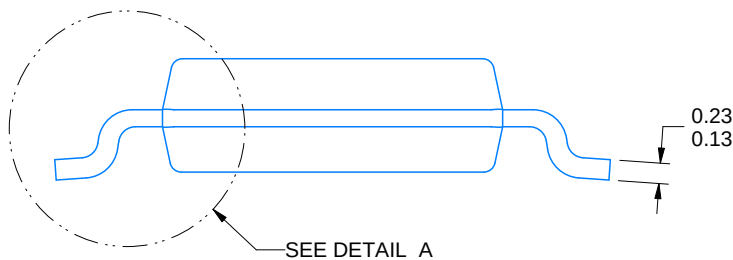
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV722QDGKRQ1	VSSOP	DGK	8	2500	366.0	364.0	50.0



VSSOP - 1.1 mm max height

Technical drawing of a 6-pin connector. The drawing includes a top view and a side view. The top view shows a rectangular body with six pins on the right side. Dimensions include a total width of 5.05 (typical) and 4.75, a pin pitch of 1.95, and a pin diameter of 0.65. A circular feature is labeled "PIN 1 INDEX AREA". The side view shows the profile of the connector with a seating plane. Callouts include "A", "B", "C", "D", "E", "F", "G", "H", "I", "J", "K", "L", "M", "N", "O", "P", "Q", "R", "S", "T", "U", "V", "W", "X", "Y", "Z", "AA", "AB", "AC", "AD", "AE", "AF", "AG", "AH", "AI", "AJ", "AK", "AL", "AM", "AN", "AO", "AP", "AQ", "AR", "AS", "AT", "AU", "AV", "AW", "AX", "AY", "AZ", "BA", "BB", "BC", "BD", "BE", "BF", "BG", "BH", "BI", "BJ", "BK", "BL", "BM", "BN", "BO", "BP", "BQ", "BR", "BS", "BT", "BU", "BV", "BW", "BX", "BY", "BZ", "CA", "CB", "CC", "CD", "CE", "CF", "CG", "CH", "CI", "CJ", "CK", "CL", "CM", "CN", "CO", "CP", "CQ", "CR", "CS", "CT", "CU", "CV", "CW", "CX", "CY", "CZ", "DA", "DB", "DC", "DD", "DE", "DF", "DG", "DH", "DI", "DJ", "DK", "DL", "DM", "DN", "DO", "DP", "DQ", "DR", "DS", "DT", "DU", "DV", "DW", "DX", "DY", "DZ", "EA", "EB", "EC", "ED", "EE", "EF", "EG", "EH", "EI", "EJ", "EK", "EL", "EM", "EN", "EO", "EP", "EQ", "ER", "ES", "ET", "EU", "EV", "EW", "EX", "EY", "EZ", "FA", "FB", "FC", "FD", "FE", "FF", "FG", "FH", "FI", "FJ", "FK", "FL", "FM", "FN", "FO", "FP", "FQ", "FR", "FS", "FT", "FU", "FV", "FW", "FX", "FY", "FZ", "GA", "GB", "GC", "GD", "GE", "GF", "GG", "GH", "GI", "GJ", "GK", "GL", "GM", "GN", "GO", "GP", "GQ", "GR", "GS", "GT", "GU", "GV", "GW", "GX", "GY", "GZ", "HA", "HB", "HC", "HD", "HE", "HF", "HG", "HH", "HI", "HJ", "HK", "HL", "HM", "HN", "HO", "HP", "HQ", "HR", "HS", "HT", "HU", "HV", "HW", "HX", "HY", "HZ", "IA", "IB", "IC", "ID", "IE", "IF", "IG", "IH", "II", "IJ", "IK", "IL", "IM", "IN", "IO", "IP", "IQ", "IR", "IS", "IT", "IU", "IV", "IW", "IX", "IY", "IZ", "JA", "JB", "JC", "JD", "JE", "JF", "JG", "JH", "JI", "JJ", "JK", "JL", "JM", "JN", "JO", "JP", "JQ", "JR", "JS", "JT", "JU", "JV", "JW", "JX", "JY", "JZ", "KA", "KB", "KC", "KD", "KE", "KF", "KG", "KH", "KI", "KJ", "KK", "KL", "KM", "KN", "KO", "KP", "KQ", "KR", "KS", "KT", "KU", "KV", "KW", "KX", "KY", "KZ", "LA", "LB", "LC", "LD", "LE", "LF", "LG", "LH", "LI", "LJ", "LK", "LL", "LM", "LN", "LO", "LP", "LQ", "LR", "LS", "LT", "LU", "LV", "LW", "LX", "LY", "LZ", "MA", "MB", "MC", "MD", "ME", "MF", "MG", "MH", "MI", "MJ", "MK", "ML", "MM", "MN", "MO", "MP", "MQ", "MR", "MS", "MT", "MU", "MV", "MW", "MX", "MY", "MZ", "NA", "NB", "NC", "ND", "NE", "NF", "NG", "NH", "NI", "NJ", "NK", "NL", "NM", "NN", "NO", "NP", "NQ", "NR", "NS", "NT", "NU", "NV", "NW", "NX", "NY", "NZ", "OA", "OB", "OC", "OD", "OE", "OF", "OG", "OH", "OI", "OJ", "OK", "OL", "OM", "ON", "OO", "OP", "OQ", "OR", "OS", "OT", "OU", "OV", "OW", "OX", "OY", "OZ", "PA", "PB", "PC", "PD", "PE", "PF", "PG", "PH", "PI", "PJ", "PK", "PL", "PM", "PN", "PO", "PP", "PQ", "PR", "PS", "PT", "PU", "PV", "PW", "PX", "PY", "PZ", "QA", "QB", "QC", "QD", "QE", "QF", "QG", "QH", "QI", "QJ", "QK", "QL", "QM", "QN", "QO", "QP", "QQ", "QR", "QS", "QT", "QU", "QV", "QW", "QX", "QY", "QZ", "RA", "RB", "RC", "RD", "RE", "RF", "RG", "RH", "RI", "RJ", "RK", "RL", "RM", "RN", "RO", "RP", "RQ", "RR", "RS", "RT", "RU", "RV", "RW", "RX", "RY", "RZ", "SA", "SB", "SC", "SD", "SE", "SF", "SG", "SH", "SI", "SJ", "SK", "SL", "SM", "SN", "SO", "SP", "SQ", "SR", "SS", "ST", "SU", "SV", "SW", "SX", "SY", "SZ", "TA", "TB", "TC", "TD", "TE", "TF", "TG", "TH", "TI", "TJ", "TK", "TL", "TM", "TN", "TO", "TP", "TQ", "TR", "TS", "TT", "TU", "TV", "TW", "TX", "TY", "TZ", "UA", "UB", "UC", "UD", "UE", "UF", "UG", "UH", "UI", "UJ", "UK", "UL", "UM", "UN", "UO", "UP", "UQ", "UR", "US", "UT", "UU", "UV", "UW", "UX", "UY", "UZ", "VA", "VB", "VC", "VD", "VE", "VF", "VG", "VH", "VI", "VJ", "VK", "VL", "VM", "VN", "VO", "VP", "VQ", "VR", "VS", "VT", "VU", "VV", "VW", "VX", "VY", "VZ", "WA", "WB", "WC", "WD", "WE", "WF", "WG", "WH", "WI", "WJ", "WK", "WL", "WM", "WN", "WO", "WP", "WQ", "WR", "WS", "WT", "WU", "WV", "WW", "WX", "WY", "WZ", "XA", "XB", "XC", "XD", "XE", "XF", "XG", "XH", "XI", "XJ", "XK", "XL", "XM", "XN", "XO", "XP", "XQ", "XR", "XS", "XT", "XU", "XV", "XW", "XX", "XY", "XZ", "YA", "YB", "YC", "YD", "YE", "YF", "YG", "YH", "YI", "YJ", "YK", "YL", "YM", "YN", "YO", "YP", "YQ", "YR", "YS", "YT", "YU", "YV", "YW", "YX", "YY", "YZ", "ZA", "ZB", "ZC", "ZD", "ZE", "ZF", "ZG", "ZH", "ZI", "ZJ", "ZK", "ZL", "ZM", "ZN", "ZO", "ZP", "ZQ", "ZR", "ZS", "ZT", "ZU", "ZV", "ZW", "ZX", "ZY", "ZZ".



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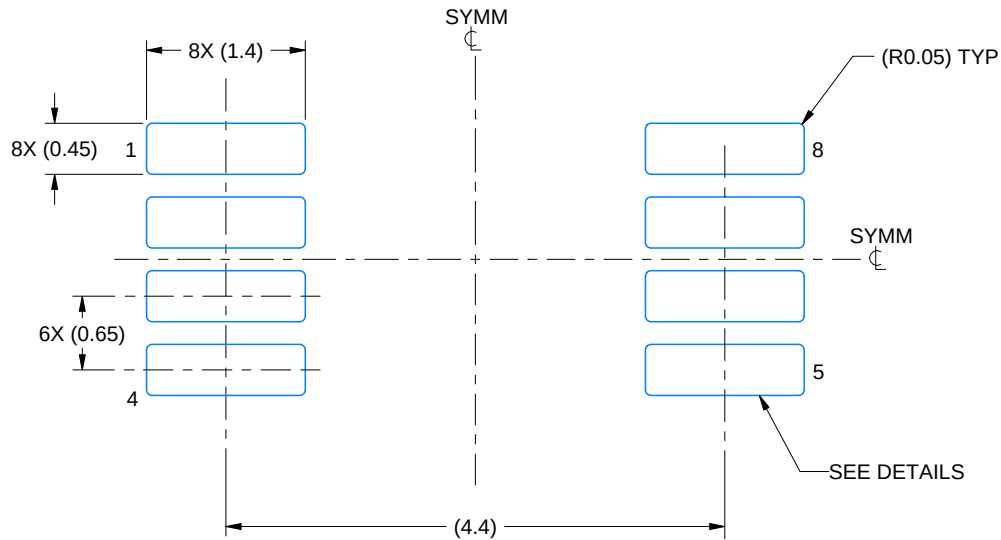
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EXAMPLE BOARD LAYOUT

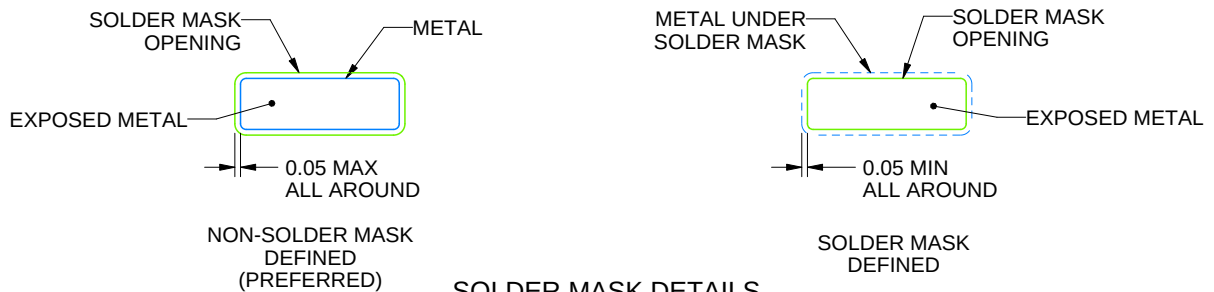
DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

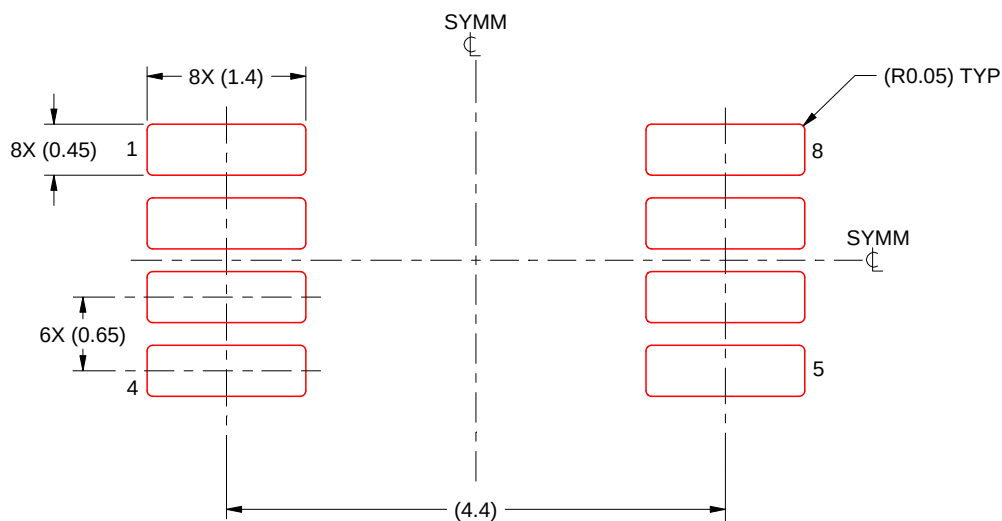
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

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